

FEATURES

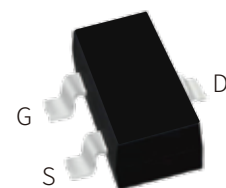
| V_{DS} (V) = 30V, I_D = 5.8 A (V_{GS} = 10V)

| $R_{DS(ON)}$ < 32m Ω (V_{GS} = 10V)

| $R_{DS(ON)}$ < 36m Ω (V_{GS} = 4.5V)

| $R_{DS(ON)}$ < 56m Ω (V_{GS} = 2.5V)

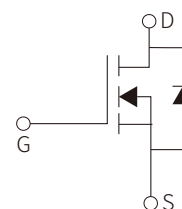
| Meet AEC-Q101 Requirements



SOT-23-3L



Marking



Schematic Symbol

APPLICATION

| This device is suitable for use as a load switch or in PWM applications, Meet the stringent requirements of automotive applications

APPROVALS

RoHS	Compliance with 2011/65/EU
HF	Compliance with IEC61249-2-21:2003

ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Drain Current-Continuous	I_D	5.8	A
Drain Current-Continuous	$I_D(T_a=70^{\circ}\text{C})$	4.9	A
Pulsed Drain Voltage	I_{DM}	30	A
Gate-Source Voltage	V_{GS}	± 12	V
Total Power Dissipation	P_D	1.4	W
Total Power Dissipation	$P_D(T_a=70^{\circ}\text{C})$	1.0	W
Operating and Storage Junction Temperature	T_J, T_{STG}	-55 to 150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=24V, V_{GS}=0V$			1	μA
		$V_{DS}=24V, V_{GS}=0V, T_J=55^{\circ}\text{C}$			5	μA
Gate-Body Leakage	I_{GSS}	$V_{GS}=\pm 12V, V_{DS}=0V$			± 0.1	μA
On-State Drain Current	$I_{D(ON)}$	$V_{GS}=4.5V, V_{DS}=5V$	30			A
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.65	1.1	1.45	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=5.8A$		29	32	m Ω
		$V_{GS}=10V, I_D=5.8A, T_J=125^{\circ}\text{C}$			39	
		$V_{GS}=4.5V, I_D=5A$		32	36	
		$V_{GS}=2.5V, I_D=4A$		40	56	
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=5A$	10	15		S
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=1A$		0.77	1	V
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, F=1.0\text{MHz}$		823	1030	pF
Output Capacitance	C_{oss}			99		
Reverse Transfer Capacitance	C_{rss}			77		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, R_L=2.7\Omega$ $V_{DS}=15V, R_{GEN}=3\Omega$		3.3	5	ns
Turn-On Rise Time	t_r			4.8	7	
Turn-Off Delay Time	$t_{d(off)}$			26.3	40	
Turn-Off Fall Time	t_f			4.1	6	
Gate resistance	R_g	$V_{GS}=0V, V_{DS}=0V, F=1.0\text{MHz}$		1.2	3.6	Ω
Total Gate Charge	Q_g	$V_{GS}=4.5V, V_{DS}=15V, I_D=5.8A$		9.7	12	nC
Gate Source Charge	Q_{gs}			1.6		
Gate Drain Charge	Q_{gd}			3.1		
Body Diode Reverse Recovery Time	t_{rr}	$I_F=5A, dI/dt=100A/\mu s$		16	20	ns
Body Diode Reverse Recovery Charge	Q_{rr}	$I_F=5A, dI/dt=100A/\mu s$		8.9	12	nC

PARAMETER CHARACTERISTIC CURVE

Figure 1

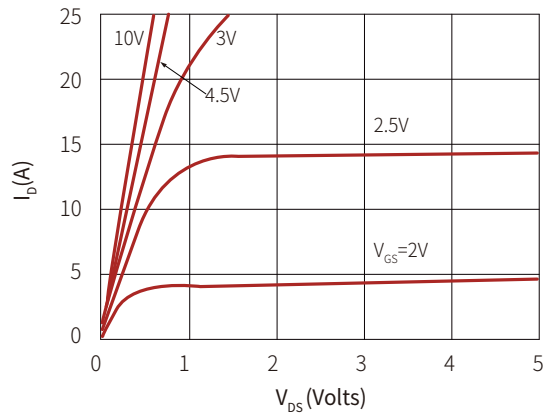


Figure 2

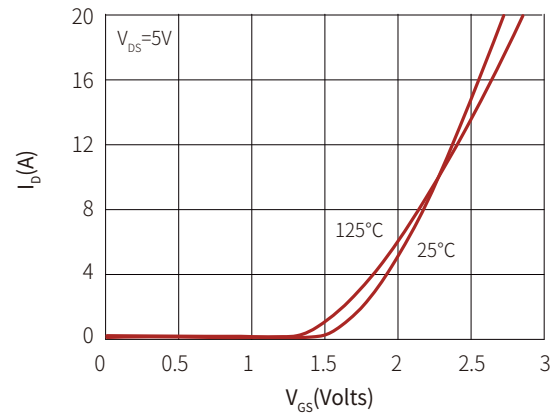


Figure 3

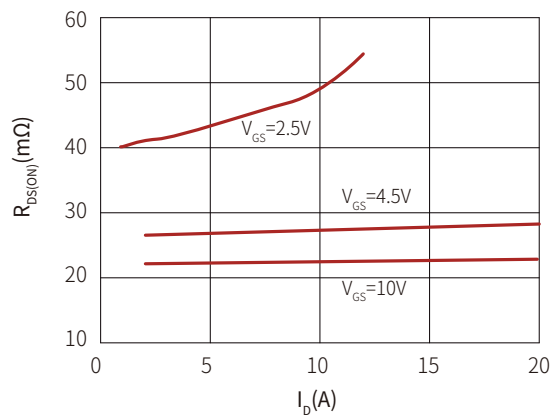


Figure 4

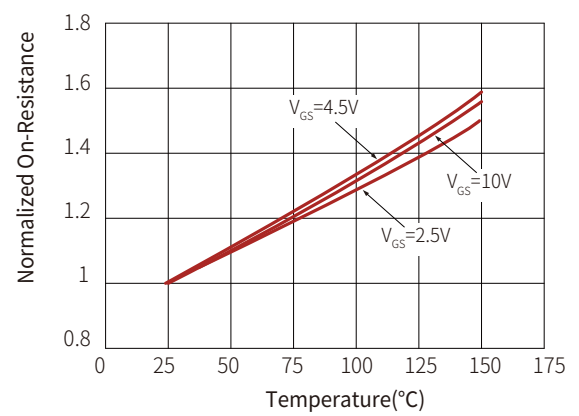


Figure 5

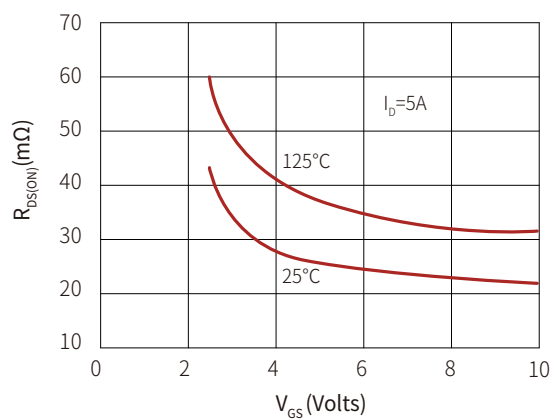


Figure 6

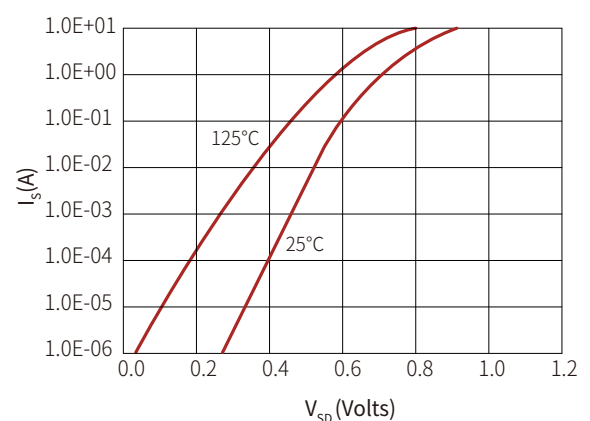
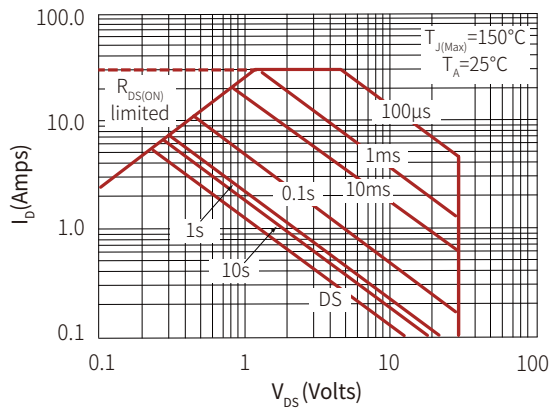
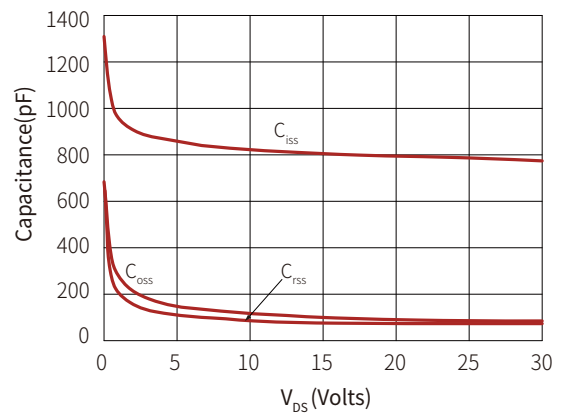
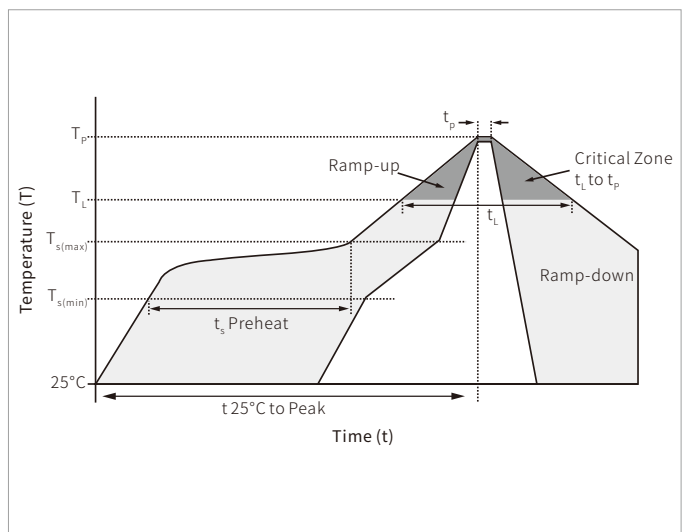


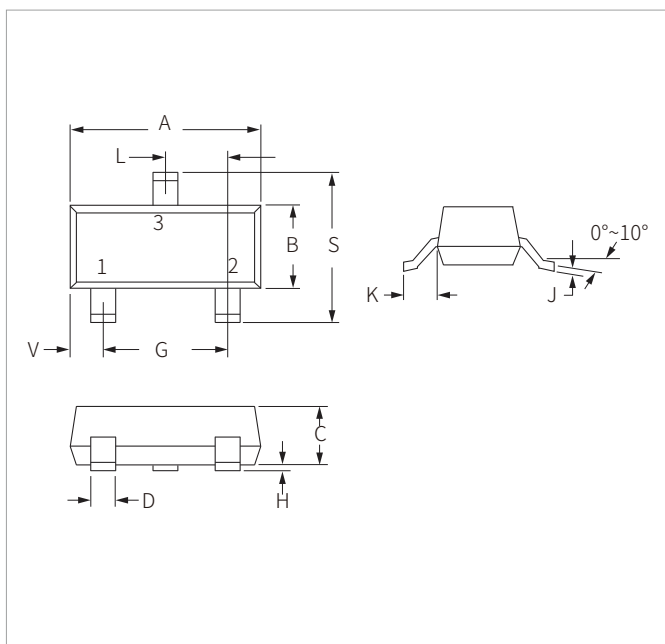
Figure 7

Figure 8


SOLDERING PARAMETERS

Reflow Condition		Lead-free assembly
Pre Heat	Temperature Max ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak $T_{s(max)}$ to T_L - Ramp-up Rate)		3°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Time (min to max) (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260°C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max.
Do not exceed		260°C

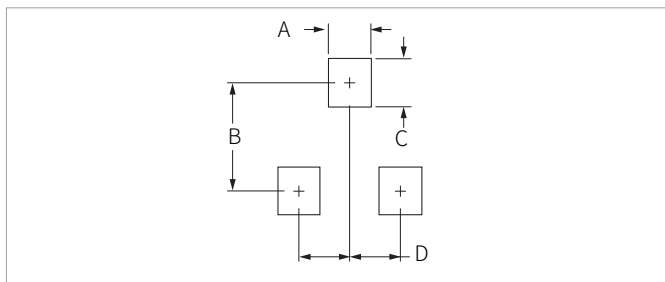


SOT-23-3L PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.80	3.15	0.110	0.124
B	1.50	1.70	0.060	0.070
C	1.00	1.30	0.039	0.051
D	0.37	0.50	0.015	0.020
G	1.78	2.10	0.070	0.083
H	0.01	0.15	0.001	0.006
J	0.08	0.18	0.003	0.007
K	0.35	0.69	0.014	0.029
L	0.89	1.02	0.035	0.040
S	2.60	3.00	0.102	0.118
V	0.45	0.60	0.018	0.024

RECOMMENDED PAD LAYOUT DIMENSIONS



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.70	1.00	0.028	0.039
B	2.30	2.50	0.090	0.098
C	0.70	1.00	0.028	0.039
D	0.80	1.10	0.032	0.043

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
SNM3400Q	SOT-23-3L	3000PCS	7"

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By QR Code

Website



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